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Kind regards,

Team Nexperia

Product data sheet

1. General description

Dual Planar Schottky barrier diode in common cathode configuration with an integrated guard ring for stress protection, encapsulated in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Low forward voltage
- Low capacitance
- AEC-Q101 qualified

3. Applications

- Ultra high-speed switching
- Line termination
- Voltage clamping
- Line termination

4. Quick reference data

Table 1. Qu	ick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I _F	forward current		-	-	200	mA
V _R	reverse voltage		-	-	30	V
Per diode						
V _F	forward voltage	I _F = 10 mA; T _{amb} = 25 °C	-	-	400	mV





Dual Schottky barrier diode

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode (diode 1)	3	К1, К2
2	A2	anode (diode 2)		
3	K1, K2	common cathode	1 ☐ ☐ 2 SC-70 (SOT323)	aaa-004975

6. Ordering information

Table 3. Ordering information				
Type number Package				
	Name	Description	Version	
1PS70SB15	SC-70	plastic surface-mounted package; 3 leads	SOT323	

7. Marking

Table 4. Marking codes	
Type number	Marking code
	[1]
1PS70SB15	7%5

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode		·			
V _R	reverse voltage		-	30	V
I _F	forward current		-	200	mA
I _{FRM}	repetitive peak forward current	t _p ≤ 1 s; δ ≤ 0.5	-	300	mA
I _{FSM}	non-repetitive peak forward current	t_p < 10 ms; $T_{j(init)}$ = 25 °C	-	600	mA
P _{tot}	total power dissipation	T _{amb} < 25 °C	-	200	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	150	°C

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Dual Schottky barrier diode

Symbol	Parameter	Conditions	Min	Max	Unit
T _{stg}	storage temperature		-65	150	°C

9. Thermal characteristics

Table 6. The	rmal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Per device							
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

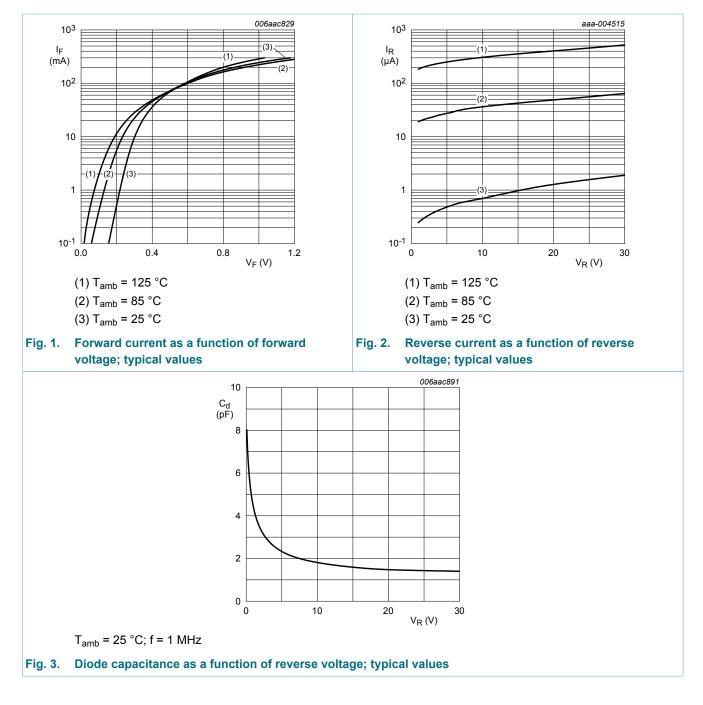
10. Characteristics

Table 7. C	haracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						_
V _F forward voltage		I _F = 0.1 mA; T _{amb} = 25 °C	-	-	240	mV
	I _F = 1 mA; T _{amb} = 25 °C	-	-	320	mV	
	I _F = 10 mA; T _{amb} = 25 °C	-	-	400	mV	
	I _F = 30 mA; T _{amb} = 25 °C	-	-	500	mV	
		I _F = 100 mA; T _{amb} = 25 °C	-	-	800	mV
I _R	reverse current	V_R = 25 V; pulsed; t _p = 300 μs; δ = 0.02 ; T _{amb} = 25 °C	-	-	2	μA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; T _{amb} = 25 °C	-	-	10	pF

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Dual Schottky barrier diode



11. Test information

11.1 Quality information

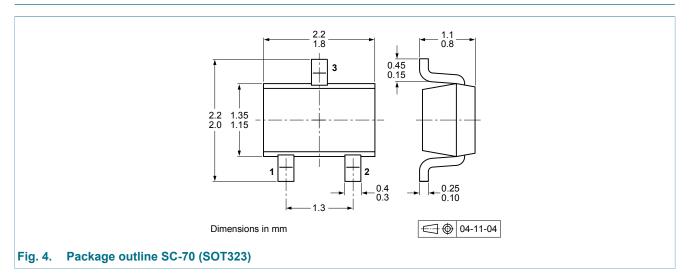
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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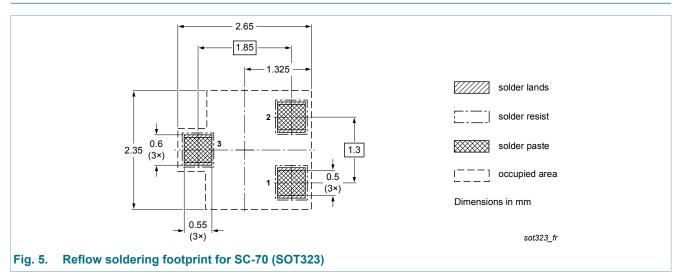
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12. Package outline



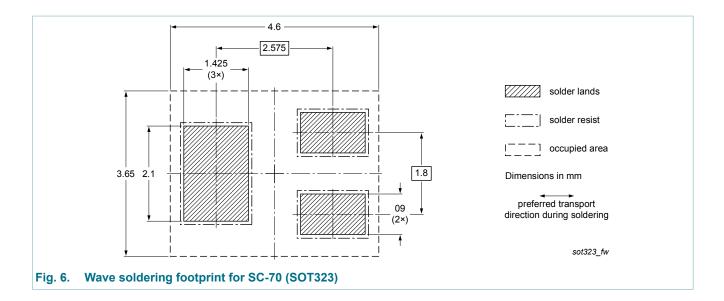
13. Soldering



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14. Revision history

Table 8. Revision his	story				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
1PS70SB15 v.2	20121217	Product data sheet	-	1PS70SB10_14_15_16 v.1	
Modifications:	of NXP Semiconduc Legal texts have be Sections 1 to 3 upda Section 4 "Quick ref Section 6 "Ordering Section 7 "Marking" Table 5 "Limiting val Figues 1, 2 and 3 up Section 11 "Test info Figure 4: supersede Section 13 "Soldering	at of this document has been redesigned to comply with the new identity guidelines Semiconductors. Its have been adapted to the new company name where appropriate. 1 to 3 updated Unick reference data" added Ordering information" added Warking" updated Limiting values": ambient temperature T _{amb} and junction temperature T _j updated			
1PS70SB10_14_15_16 v.1	19990426	Product data sheet	-	-	

Dual Schottky barrier diode

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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Product data sheet

17 December 2012

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